

BGS22W2L10

DPDT (Dual-Pole / Double-Throw) Differential RF Switch

Data Sheet

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Power Management & Multimarket

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Revision History

Previous	Previous Version: v1.3, October 11, 2012							
Page	Subjects (major changes since last revision)							
8	Updated BGS22W2L10 Block Diagram (Figure 1)							
10	Updated RF Characteristics (Table 6)							
11	Updated Pin Configuration (Table 7)							

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Last Trademarks Update 2010-06-09





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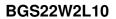
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BGS22W2L10 DPDT (Dual-Pole / Double-Throw) Differential RF Switch

1 Features

- DPDT (Dual-Pole / Double-Throw) differential RF switch
- Frequency range: 0.1 2 GHz
- High signal power up to 24 dBm
- Supply voltage 2.4 3.6 V
- · Low insertion loss
- High isolation
- Small package size of 1.55 x 1.15 mm²
- No decoupling capacitors required if no DC applied on RF lines
- · RoHS compliant package





2 Product Description

The BGS22W2L10 is a DPDT (Dual-Pole / Double Throw) RF switch which combines two differential signals into one differential output or splits one differential signal into two separate differential lines. The parallel paths of the switch are controlled simultaneously through the same signals. The switch is designed to operate in battery powered applications with a supply voltage range of 2.4 - 3.6 V. The highly symmetric design ensures best phase- and amplitude accuracy.

A typical application is to combine two Rx paths in a mobile cellular device after the Rx filters or duplexers into one input to the tranceiver IC. The IC can also be used for a wide variety of applications switching balanced signals in a frequency range of 0.1 - 3 GHz. The RF switch is packaged in a standard RoHS compliant TSLP-10-1 package with a small outline of only 1.55×1.15 mm^2 .

No decoupling capacitors are required in typical applications as long as no DC is applied to any RF port.

Table 1: Ordering Information

Туре	Package	Marking
BGS22W2L10	TSLP-10-1	22W6



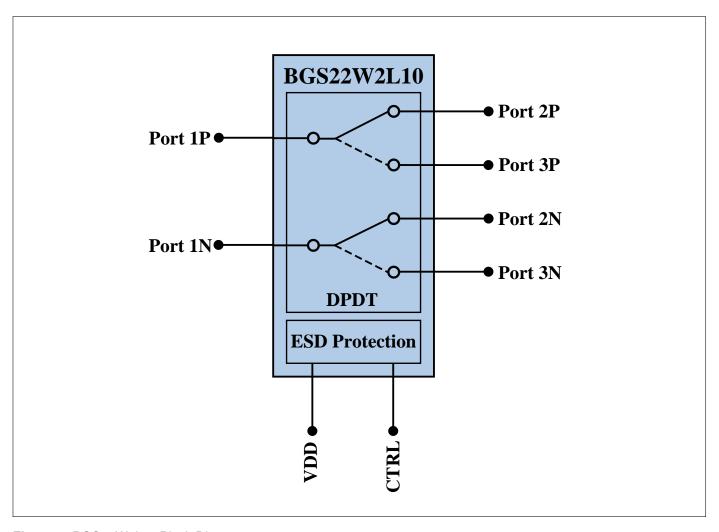


Figure 1: BGS22W2L10 Block Diagram

Table 2: Truth Table

Pin No.	CRTL
Port 1 to Port 2	0
Port 1 to Port 3	1



3 Maximum Ratings

Table 3: Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol		Values	3	Unit	Note / Test Condition	
		Min.	Тур.	Max.		rest Condition	
Supply Voltage	V_{DD}	-0.5	-	5.5	V	_	
Control Voltage	V _{Ctrl}	-0.3	-	3.6	V	_	
Storage Temperature Range	T _{STG}	-55	-	150	°C	_	
RF Input Power	P _{In}	_	-	26	dBm	_	
ESD Capability Human Body Model	V _{ESD_HBM}	1000	-	_	V	_	
Junction Temperature	T_j	_	-	125	°C	_	
Thermal Resistance Junction - Soldering	R _{thJS}	_	_	43	K/W	_	
Point							

Attention:

Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

4 Operation Ranges

Table 4: Operation Ranges

Parameter	Symbol	Symbol Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Supply Voltage	V_{DD}	2.4	_	3.6	V	_
Control Voltage Low	V _{Ctrl_L}	-0.3	_	0.4	V	_
Control Voltage High	V _{Ctrl_H}	1.2	_	V _{DD}	V	_
RF Frequency	f _{RF}	0.1	_	2	GHz	_
Ambient Temperature	$T_{\mathcal{A}}$	-30	25	85	°C	_

Table 5: RF Input Power

Parameter	Symbol	Values		Unit	Note / Test Condition	
		Min.	Тур.	Max.		
RF Input Power (50 Ω)	P _{In}	_	_	24	dBm	_



5 RF Characteristics

Table 6: RF Characteristics

Test Conditions (unless otherwise specified):

• Terminating Port Impedance: $Z_0 = 50 \Omega$

• Temperature Range: $T_A = -30 \dots +85 \, ^{\circ}\text{C}$

• Supply Voltage: $V_{DD} = 2.4 - 3.6 V$

• Input Power: $P_{IN} = 0 dBm$

Parameter	Symbol		Values	i	Unit	Note / Test Condition	
		Min.	Min. Typ. Max.				
Insertion Loss	1	-		1			
	,,	0.17	0.22	0.36	dB	824 - 915 MHz	
	IL	0.32	0.39	0.61	dB	1710 - 1910 MHz	
Insertion Loss ¹		-					
	,,	0.20	0.22	0.30	dB	824 - 915 MHz	
	IL	0.36	0.39	0.50	dB	1710 - 1910 MHz	
Return Loss		ı					
	DI	22	27	36	dB	824 - 915 MHz	
	RL	14	17	20	dB	1710 - 1910 MHz	
Isolation		1		-1	-		
	100	31	35	39	dB	824 - 915 MHz	
	ISO	22	27	30	dB	1710 - 1910 MHz	
P0.1 dB Compre	ssion Poin	t ¹		l	-	1	
	P _{0.1dB}	28	28.5	29	dBm	1000 MHz	
Harmonic Gene	ration up to	12.75 GI	Hz	'	'		
Any Path	P _{Harm}	-95	-85	-80	dBc	21 dBm, 50Ω, 25 % Duty Cycle	
Intermodulation	Distortion	in Rx Ba	nd ¹	'	'		
IMD2_Low	P_{IMD2_L}	-125	-115	-110	dBm		
IMD3	P_{IMD3}	-125	-115	-110	dBm	Tx = 10 dBm, Interferer = -15 dBm	
IMD2_High	P _{IMD2_H}	-125	-115	-110	dBm		
Switching Time		t Consur	nption	'	'		
RF Rise Time	t _{10%-90%}	_	0.35	1	μ s	10% - 90% of RF Signal	
Ctrl to RF Time	t _{Ctrl-RF}	_	0.6	1.5	μ s	50% of Ctrl Signal to 90% of RF	
						Signal	
Supply Current	I_{DD}	75	120	350	μ A	_	
Phase Error ¹	I	ı					
Between any	Ph _{Err}	0.3	1	1.9	Deg.	_	
two Paths							

Note: All electrical characteristics are measured with all RF ports terminated by 50 Ω loads.

¹ $T_A = +25 \,{}^{\circ}\,C, \ V_{DD} = 3 \ V$



6 Package Outline and Pin Configuration

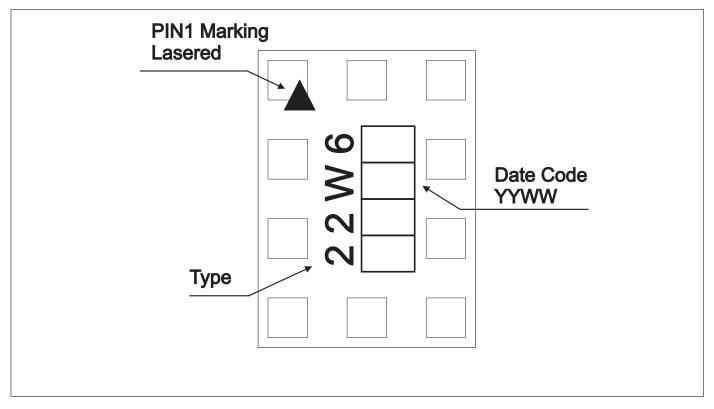


Figure 2: Marking Layout (top view)

Table 7: Pin Configuration

Pin	Name	Pin	Buffer	Function
No.		Туре	Туре	
1	Port 3P	I/O		Differential Output P of Port 3
2	GND	GND		Ground Pin
3	GND	GND		Ground Pin
4	Port 2N	I/O		Differential Output N of Port 2
5	Port 2P	I/O		Differential Output P of Port 2
6	CTRL	1		Control Voltage
7	Port 1P	I/O		Differential Input P of Port 1
8	Port 1N	I/O		Differential Input N of Port 1
9	VDD	PWR		Supply Voltage
10	Port 3N	I/O		Differential Output N of Port 3



Table 8: Mechanical Data

Parameter	Symbol	Value	Unit
Package X-Dimension	X	1.55 ± 0.05	mm
Package Y-Dimension	Υ	1.15 ± 0.05	mm
Package Area	Α	1.783	mm ²
Package Height	Н	0.39 +0.01/-0.03	mm

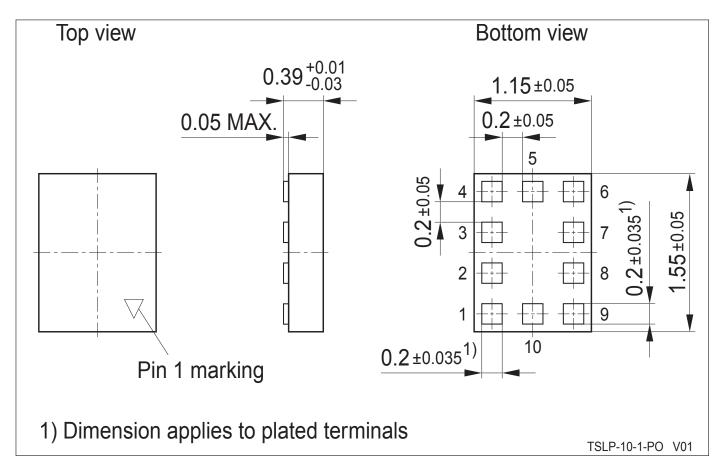


Figure 3: TSLP-10-1 Package Outline (top, side and bottom view)



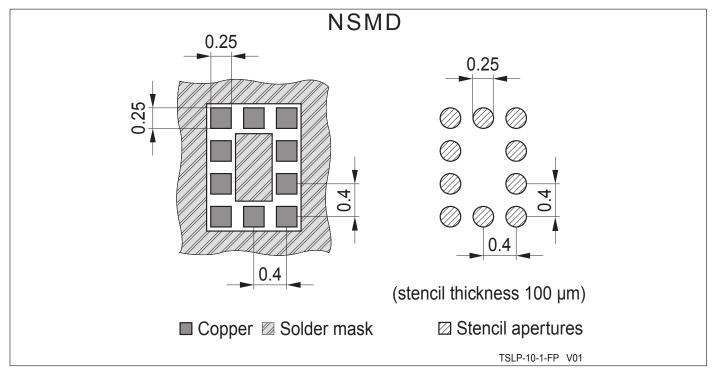


Figure 4: Footprint TSLP-10-1

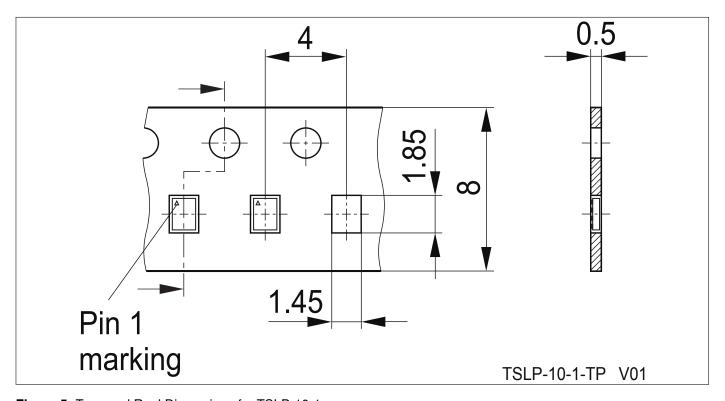


Figure 5: Tape and Reel Dimensions for TSLP-10-1

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